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Luminescent Properties and Energy Level Structure of CaZnOS:Eu²⁺

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8 Abstract

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10 In this work it is shown that CaZnOS:Eu²⁺ has no Eu²⁺ emission even at low temperature. The observed and earlier reported red emission originates from a CaS: Eu^{2+} impurity 11 phase. By means of washing the as-prepared samples with diluted nitride acid, we are 12 able to remove the CaS impurity and get the pure CaZnOS. A clear relation was found 13 between the red emission intensity, the CaS XRD line intensities and the nitric acid 14 solution washing time, with zero intensity after prolonged washing. Later, a so-called 15 VRBE (vacuum referred binding energy)-diagram was constructed showing the energy 16 of the 4fⁿ and 4fⁿ⁻¹5d¹ states of the divalent and trivalent rare earth ions as dopants in 17 CaZnOS with respect to the vacuum energy. This diagram shows that the 5d-levels of 18 Eu²⁺ are located in the conduction band, which explains the absence of $5d \rightarrow 4f$ emission. 19 By comparing the VRBE diagram with diagrams of other related compounds like CaO, 20 CaS, ZnO and ZnS it becomes clear that the Eu²⁺ luminescence quenching is caused by a 21 22 low lying conduction band, typical for Zn-based compounds.

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25 **1. Introduction**

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Red light emitting phosphors are of interest for their applications in white light-emitting 27 diodes[1] and are considered for their potential to increase the rate of photosynthesis in 28 29 algae systems[2, 3]. LEDs are energy efficient light sources that have found a wide range of applications since their discovery. Currently the most common method to produce 30 white LEDs is by combining a blue LED chip (450-470 nm) with a yellow phosphor[3]. 31 This however gives a cold white light and in order to produce a warmer colour of light a 32 red emitting phosphor is needed. When Eu²⁺ is doped in a proper host lattice it is known 33 to accommodate this red light emission[4]. 34

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The emission of Eu²⁺ arises from a 5d \rightarrow 4f transition. As the 5d electronic level is not 36 shielded from the surrounding ligands^[5], its energy varies widely with the lattice in 37 which the Eu²⁺ ions are doped and is determined by the combined effect of the centroid 38 shift and the crystal field splitting of the 5d states. The centroid shift is the lowering of 39 average energy of the 5d states compared to a free ion. The centroid shift is larger when 40 Eu is coordinated by S ions compared to O ions because it follows the nephelauxetic 41 series[6]. The crystal field splitting is caused by the electron repulsion between the 5d 42 states and the surrounding ligands and is therefore affected by the size and symmetry of 43 the Eu lattice site. 44

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CaS:Eu²⁺ is a commercially available red phosphor emitting at a maximum of 650nm.
CaZnOS:Eu²⁺ has been reported to emit red luminescence that is practically the same as
CaS:Eu²⁺ [3, 7]. In this article the two materials will be compared because it is not
expected that two significantly difference between Eu lattice sites in CaS and CaZnOS

would give the same emission. A detailed analysis of phase pure Eu^{2+} , Eu^{3+} and Yb^{3+} doped CaZnOS powder samples will lead to the conclusion that CaZnOS: Eu^{2+} does not have Eu^{2+} emission and that the red emission accredited to CaZnOS: Eu^{2+} originates from a small quantity of CaS: Eu^{2+} impurity phase.

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2. Experimental methods

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CaZnOS has been synthesized by the following reaction: $ZnS + CaO \rightarrow CaZnOS$. The 57 synthesis of pure phase CaZnOS is challenging because of the decomposition reaction 58 above 1370 K: CaZnOS \rightarrow ZnO + CaS. Additionally ZnO easily decomposes to O₂ gas and 59 Zn vapor when heated above 1205 K under reducing atmosphere[8], and this 60 decomposition is accelerated by the presence of carbonate salts such as $CaCO_3$ [9]. Above 61 1180 K ZnS and CaO (i.e. CaCO₃ after thermal decomposition) react towards CaS and 62 ZnO, which in time decomposes to zinc vapor[10]. Since a reducing environment is 63 required when Eu_2O_3 is used as a starting material the synthesis towards a pure phase 64 CaZnOS:Eu²⁺ is difficult because a small CaS phase is almost always present. 65 Nevertheless several studies on CaZnOS report a pure phase without CaS impurities [3, 66 11, 12]. In this research, obtained CaZnOS samples were successfully purified by 67 washing with a solution of water and nitric acid, a method not yet used for CaZnOS. With 68 this method a series of CaZnOS:Eu2+ phosphors with decreasing CaS content was 69 synthesized to investigate the luminescent properties as a function of the amount of CaS 70 71 impurity.

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For the synthesis of CaZnOS:Eu²⁺, CaCO₃ (99.95%, Alfa Aesar), ZnS (99.99%, Alfa Aesar) 73 and Eu₂O₃ (99.99%, Sigma Aldrich) were weighted in stoichiometric quantities and 74 extensively ground with a pestle and mortar and placed in an Al₂O₃ crucible which was 75 placed in a larger crucible and heated at 900°C for 32 hours under a 7% H_2 / 93% N_2 76 reducing atmosphere in a tube furnace and subsequently cooled down to room 77 temperature. For the undoped CaZnOS host an 8-hour reaction time was used at the 78 same conditions. The doping concentration of Eu was 4 mol%. The CaS:Eu²⁺ was 79 80 obtained as a commercial product from Intematix. The washing of the product was 81 performed by adding a 1% nitric acid solution of water to the sample, followed by stirring, filtration and washing with acetone. For the synthesis of the Eu³⁺ doped pure 82 phase CaZnOS, the host lattice was synthesized first. After that, Eu₂O₃ was added in the 83 as-prepared CaZnOS and re-annealed at the same temperature for 4 hours in the N_2 84 atmosphere. 85

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87 The XRD measurements were performed by a PANalytical XPert Pro XRD spinner between a 2θ value of 5° and 80° in a 1-hour measurement. The radiation source is a Cu 88 K α anode at 45 kV and 40 mA with $\lambda(K\alpha_1) = 0.154060$ nm and $\lambda(K\alpha_2) = 0.154443$ nm. 89 The background determination was performed with Highscore software. Emission 90 91 spectra were recorded of powder samples that were compressed to pills and placed in a rotating sample holder to minimize any effects from sample holder displacement. 92 Sample were excited by a monochromatic Expla OPO laser and the emission spectra 93 were collected with an Ocean Optics QE65000 Spectrometer. For low temperature 94 measurements, spectra were obtained by pelletizing the sample and irradiated with a 95 150W Xenon arc lamp (Hamamatsu L2273). A Gemini 180 Monochromater was used to 96 tune the excitation wavelength. The emission spectra were obtained by an Acton 97 98 Sp2300 Spectrometer. The excitation spectra were calibrated by the Xe lamp spectrum and the emission spectra were calibrated by the detector response curve. Diffuse 99 reflection spectra were obtained by placing the sample in a sample holder and 100 irradiating it with an Acton Deuterium lamp. The reflection spectra were measured by 101

an Ocean Optics QE65000 Spectrometer. $BaSO_4$ was used as a reference for the reflection measurement.

3. Results

In Figure 1 the XRD spectra of four samples are presented: (a) CaZnOS (washed), (b) CaZnOS:Eu²⁺ (unwashed), (c) CaZnOS:Eu²⁺ (washed) and (d) CaS:Eu²⁺. Spectra (a) and (d) show the same lines as the reference spectra for CaZnOS and CaS obtained from the Pearson's Crystal Database[13]. Many peaks of CaS overlap with those of CaZnOS, however the peak at 45° is unique for CaS and is therefore considered the best indicator to determine the amount of CaS impurity phase within the CaZnOS samples.



Figure 1. XRD spectra of : (a) CaZnOS (washed), (b) CaZnOS;Eu²⁺ (unwashed), CaZnOS:Eu²⁺ (washed)
 and (d) commercial CaS:Eu²⁺.

In Figure 2, a close-up of the 45° peak in the XRD spectra of a series of CaZnOS samples
with increasing washing time is presented to demonstrate the decreasing CaS line at
45°. The CaZnOS:Eu²⁺ samples are labelled 1 through 4 referring to the unwashed
(spectrum 4), the once washed (3), and the thrice washed (2) sample. Sample (1) was
washed until a pure phase CaZnOS was obtained.



Figure 2. Zoom in on the 45° XRD peak intensity as a function of washing time for the unwashed (4),
once washed (3) and thrice washed (2) sample. Sample (1) was washed until a pure phase CaZnOS
was obtained.

A comparison between the optical properties of CaZnOS (washed), CaZnOS;Eu²⁺ (unwashed), pure phase CaZnOS:Eu²⁺ (washed) and CaS:Eu²⁺ was made. In Figure 3 the diffuse reflection spectra of the four samples are presented. An absorption band between 400 and 600 nm in CaS is clearly visible in spectrum labelled 4 as expected . No Eu-related absorption bands can be seen in the undoped CaZnOS sample (spectrum 1). The phase pure CaZnOS: Eu^{2+} sample shows an absorption band peaking at 380nm as can be seen from spectrum 3. We assign this band to $4f \rightarrow 5d$ absorption by Eu²⁺ in CaZnOS. The absorption features of the unwashed CaZnOS:Eu²⁺ sample (spectrum 2) of which the XRD spectra has shown that it contained CaS:Eu²⁺, can nicely be explained by a combination of bands due to Eu²⁺ in CaS and CaZnOS. Spectra were not plotted beyond 600 nm as the measured diffusely reflected light was too much contaminated with the red luminescence from Eu²⁺. This can already be seen from the too high diffuse reflection values for spectrum 2 towards 600 nm. Spectra 1, 2, and 3 have a short wavelength absorption onset near 280-290nm that marks the fundamental absorption onset E_{fa} . An additional absorption band marked A for spectra 1 and 3 has unknown origin.



Figure 3. Normalized diffuse reflection spectra for CaZnOS (black curve labelled 1), CaZnOS:Eu²⁺with
 CaS:Eu²⁺ (red curve labelled 2), CaZnOS:Eu²⁺ (blue curve labelled 3) and CaS:Eu²⁺ (purple curve
 labelled 4).

In Figure 4 the emission of the four samples with decreasing CaS phase is presented
 under 500 nm laser excitation in the absorption band of Eu²⁺ in CaS:Eu²⁺. The intensity
 of emission decreases rapidly with decreasing CaS content.



Figure 4. Emission spectra excited at 500 nm for the unwashed (4), once washed (3), and thrice (2) washed samples. Sample (1) was washed until a pure phase CaZnOS was obtained.



Figure 5. Luminescence excitation spectra of CaZnOS:Yb³⁺ (a), CaZnOS:Eu³⁺ (b) and undoped CaZnOS
 (c).

We did not observe any luminescence on excitation in the 380nm 5d absorption band of CaZnOS, not even at 10K. Such absence can be explained when the lowest energy 4f65d excited state of Eu²⁺ is located close or above the conduction band bottom[14]. In order to verify this, luminescence excitation spectra were recorded on samples doped with Eu³⁺ and Yb³⁺ to obtain the VB \rightarrow Ln³⁺ charge transfer energies of these ions as well as an undoped sample to obtain the exciton- and bandgap energy of CaZnOS. These energies can be used to construct a so-called vacuum referred binding energy diagram (VRBE) that provides the location of all lanthanide ground and excited states and the host valence band and conduction band states with respect to the vacuum level. All samples were washed and free from any CaS impurity phase. The results are presented in Figure 5.

Figure 5b shows the excitation spectra of 627 nm Eu^{3+} emission at 10K. The 0.55 eV broad band at 315 nm (3.9 eV) is attributed to the valence band to Eu^{3+} charge transfer (CT) transition. At 270 nm (4.6 eV) the host exciton band is observed. This peak can be observed more clearly in the undoped sample of Figure 5c when monitoring hostrelated emission at 10 K around 450nm. This onset of this peak near 285 nm is the optical bandgap or fundamental absoption threshold E_{fa} of CaZnOS. The energy agrees

with the absorption band onset found for CaZnOS:Eu²⁺ in the diffuse reflection spectra of 272 Figure 3. The optical bandgap of CaZnOS is reported in literature with different values 273 between 3.7 and 4.3 eV[11-13]. The bandgap of CaS is reported at 4.9 eV[15]. The CT-274 band of Yb^{3+} is always expected at about 0.4 eV higher energy than that of Eu³⁺ [16] and 275 is therefore anticipated at 288 nm. Figure 5a shows the excitation spectrum monitoring 276 the $4f_{5/2} \rightarrow 4f_{7/2}$ emission of Yb³⁺. Besides the host exciton band at 275 nm a broad band 277 centred around 300 nm (4.2 eV) is observed within an acceptable range of the predicted 278 279 value.

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4. Discussion

The experimental data presented in this work strongly suggest that the 650 nm 282 283 emission that was accredited to $CaZnOS:Eu^{2+}[3, 7, 12]$ is actually from samples that contain small quantities of a CaS:Eu²⁺ impurity phase. CaZnOS:Eu²⁺ samples that are 284 washed with nitric acid solution have no longer any XRD lines characteristic for CaS nor 285 have any red emission at 650 nm. Also the diffuse reflection spectrum of a washed and 286 phase pure CaZnOS:Eu²⁺ sample does not have the characteristic absorption bands of 287 Eu^{2+} in CaS between 400 and 600 nm but instead it has a band at much shorter 288 wavelength peaking at 380nm (3.3 eV). 289

Based on the collected spectroscopic data presented above, the vacuum referred binding 291 292 energy diagram for CaZnOS can be constructed. The energy-values used to construct the diagram in Figure 6 are indicated by the vertical arrows 1, 2, 3 and 4 that represent the 293 host exciton creation energy of 4.5 eV, the $4f^7 \rightarrow 4f^6[^7F_0]5d^1$ energy of 2.6 eV, the Eu³⁺ and 294 Yb³⁺ CT energies respectively. The energy difference between the Eu²⁺ ground state and 295 Eu^{3+} ground state, the so-called U-value in the chemical shift model, [17, 18] was taken 296 as 6.4 eV which is the average of the values that pertain to CaO, ZnO, CaS, and ZnS 297 presented below. The electron-hole binding energy in the host exciton is assumed to be 298 299 about 4% of the exciton creation energy. It is evident that the lowest 5d state of Eu^{2+} in CaZnOS is well above the bottom of the conduction band, which implies that upon 300 301 excitation of the 5d state, the electron will immediately delocalise into the conduction without Eu²⁺ 5d \rightarrow 4f emission even at 10 K₄ 302





It is instructive to compare the VRBE-diagrams of the related compounds CaO, CaS, ZnO,ZnS and CaZnOS.

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The VRBE-diagrams of CaS and ZnO were published earlier [19, 20]. In electrochemistry the top of the valence band for ZnS is at about 2.36 eV below the H⁺/H₂ redox potential [21] which brings it at -6.8 eV on the VRBE scale. We further used the 3.86 eV for the host exciton creation energy with an exciton binding energy of 40 meV from Hoshina *et al.* [22]. In CaO the exciton creation peak is at 6.94 eV [23] and the VB \rightarrow Eu³⁺ charge transfer band near 250nm (4.96 eV)[24-26]. For the U-parameter a value of 6.3 eV was assumed and the 4f⁷ \rightarrow 4f⁶[⁷F₀]5d¹ energy is 1.85 eV[24].

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In figure 8 we present the VRBE diagrams stacked next to each other. It shows the top of the valence band, the VRBE in the Eu^{2+} 4f⁷ ground state and when available in the 4f⁶[⁷F₀]5d₁ state, the VRBE in the host exciton state and at the bottom of the conduction band. The conduction band bottom for CaZnOS falls in between that for ZnO and CaS. Something similar applies to the top of the valence band. For sulfides it is usually at -6 eV and for oxides between -8 eV and -9 eV. The top of the valence band in CaZnOS falls in between that of a CaS and CaO or ZnS and ZnO.

From a study of Eu in more than 100 different compounds it was found that the VRBE in 341 the lowest 5d state is on average near -1 eV with a tendency to decrease with smaller 342 value for the U-parameter[27]. The level locations for CaO, CaZnOS and CaS in Figure 7 343 agree with that finding. The absence of Eu²⁺ emission in CaZnOS is then caused by a low 344 lying conduction band bottom like in ZnO. On replacing oxygen for sulphur the 345 346 conduction band moves upward. For ZnS Eu^{2+} emission is still not observed, but interestingly the Eu²⁺ emission starts to appear for nanosized particles where due to 347 band gap widening the conduction band moves to above the the Eu^{2+} 5d-level [28]. 348 349



370 Figure 7. Energy levels of Eu²⁺ in CaO, ZnO, CaS and ZnS

The low lying conduction band in ZnO as compared to CaO, and in ZnS as compared to CaS means that the electron is stronger bonded in the 4s conduction band orbital of Zn as compared to the 4s CB orbital of Ca. This reflects the atomic properties where the 2nd ionisation potential of Zn (17.96 eV) is much higher than that of Ca (11.57 eV).

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5. Conclusion

Based on the presented experimental results it can be concluded that CaZnOS:Eu²⁺ has
no luminescence as the Eu²⁺ 5d states are located in the conduction band. The red
emission accredited to Eu²⁺ in CaZnOS in literature is in fact emission from Eu²⁺ in a CaS
impurity phase that can be washed out using acid water.

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